



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
-60V	350mΩ @ V _{GS} = -10V	-1.5A
	550mΩ @ V _{GS} = -4.5V	-1.2A

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

60V P-CHANNEL ENHANCEMENT MODE MOSFET

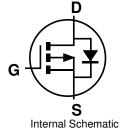
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

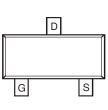
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



Top View





Top View

Ordering Information (Note 5)

Part Number	Case	Packaging
DMP6350SQ-7	SOT23	3000/Tape & Reel
DMP6350SQ-13	SOT23	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

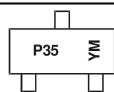
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



P35 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022
Code	С	D	E	F	G	Н		J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		V _{DSS}	-60	V	
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 7), V _{GS} = -10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	In	-1.5 -1.2	A
Pulsed Drain Current (10µs Pulse, Duty Cycle =	I _{DM}	-6	А		

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	0.72	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	$R_{ heta JA}$	176	°C/W
Power Dissipation (Note 7)	PD	1.17	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	$R_{ heta JA}$	108	°C/W
Thermal Resistance, Junction to Case	$R_{ ext{ heta}JC}$	34	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

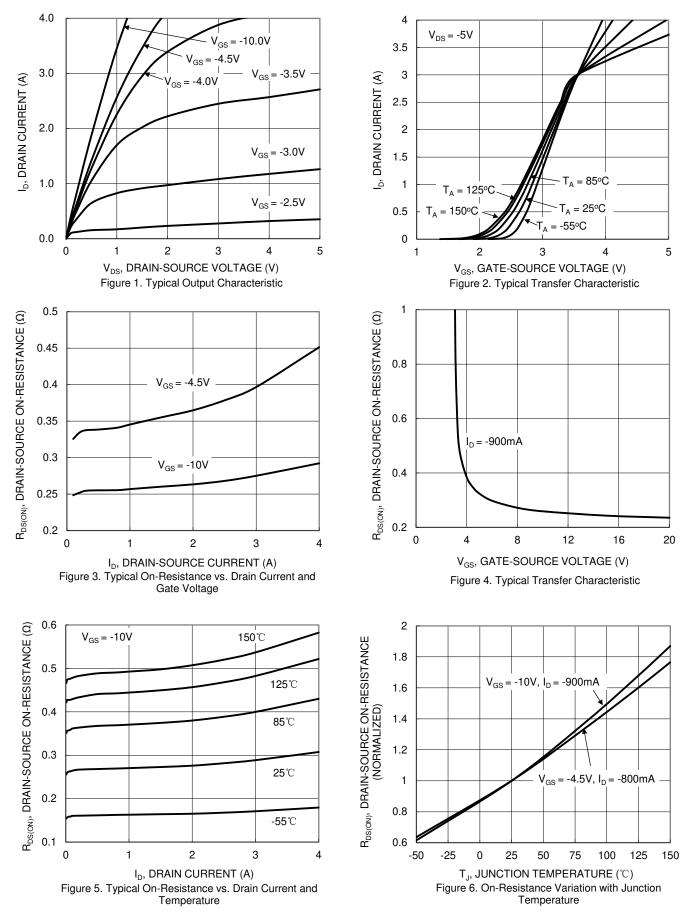
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						÷	
Drain-Source Breakdown Voltage	BV _{DSS}	-60	—	_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current TJ = +25°C	I _{DSS}	—	—	-1.0	μA	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	—	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	-1.8	-3.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance			257	350	mΩ	$V_{GS} = -10V, I_D = -0.9A$	
Static Drain-Source On-nesistance	R _{DS(ON)}	_	343	550	11122	$V_{GS} = -4.5V, I_D = -0.8A$	
Diode Forward Voltage	V _{SD}	_	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	—	206	—	pF		
Output Capacitance	C _{oss}	—	15	_	pF	− V _{DS} = -30V, V _{GS} = 0V, − f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	11	_	рF		
Gate Resistance	Rg	_	17	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	2.0	—	nC		
Total Gate Charge (V _{GS} = -10V)	Qg	_	4.1	—	nC		
Gate-Source Charge	Q _{gs}	_	0.5	—	nC	$V_{DS} = -30V, I_{D} = -0.9A$	
Gate-Drain Charge	Q _{gd}	_	0.8	—	nC		
Turn-On Delay Time	t _{D(ON)}	_	3.6	—	ns		
Turn-On Rise Time	t _R	—	3.8	—	ns	$V_{DD} = -30V, V_{GS} = -10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	12.3	_	ns	$I_{D} = -1.0A, R_{g} = 6\Omega$	
Turn-Off Fall Time	t _F	_	7.3	—	ns	7	
Body Diode Reverse Recovery Time	t _{RR}	_	8.2	_	ns	I _S = -1.0A, di/dt = -100A/µs	
Body Diode Reverse Recovery Charge	Q _{RR}	_	2.7	_	nC	I _S = -1.0A, di/dt = -100A/µs	

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



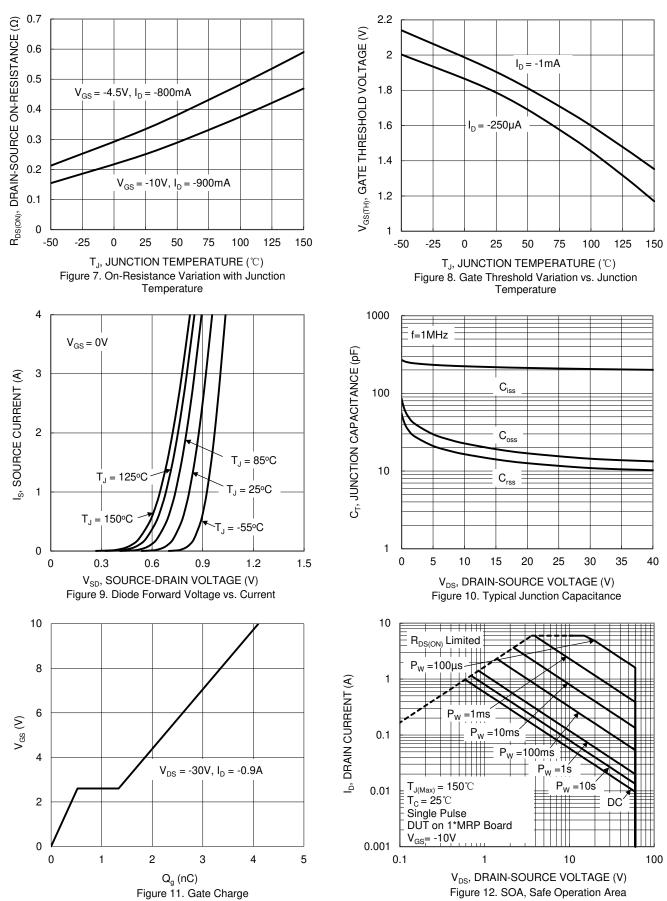
DMP6350SQ



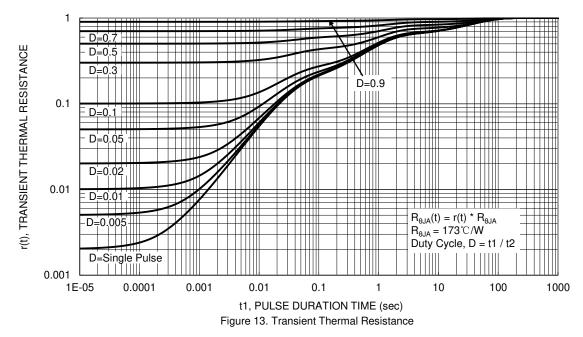
DMP6350SQ Document number: DS41140 Rev. 2 - 2



DMP6350SQ



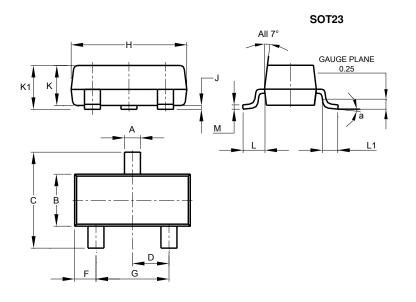






Package Outline Dimensions

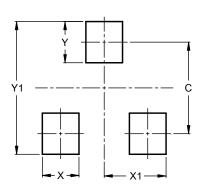
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
Н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
К	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	0°	8°							
All	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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